

Product Overview

MBRS1540: 40 V, 1.5 A Schottky Rectifier

For complete documentation, see the data sheet.

The Schottky Rectifier employs the Schottky Barrier principle in a large metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. It is ideally suited for use in low voltage, high frequency switching power supplies, low voltage converters, O-Ring diodes and polarity protection devices.

Features

- Compact Package with J-Bend Leads Ideal for Automated Handling
 - Highly Stable Oxide Passivated Junction
 - Guardring for Over-Voltage Protection
 - Low Forward Voltage Drop
 - Mechanical Characteristics:
 - Case: Molded Epoxy
 - Epoxy Meets UL94, VO at 1/8"
 - Weight: 95 mg (approximately)
 - Cathode Polarity Band
 - Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
 - Available in 12 mm Tape, 2500 Units per 13" Reel, Add "T3" Suffix to Part Number
- For more features, see the data sheet

Part Electrical Specifications

Product	Pricing (\$/Unit)	Compliance	Status	Configuration	V_{RRM} Min (V)	V_F Max (V)	I_{RM} Max (μ A)	$I_{O(ree)}$ Max (A)	I_{FSM} Max (A)	t_r Max (ns)	C_j Max (pF)	Package Type
MBRS1540T3G	0.1428	Pb-free Halide free non AEC-Q and PPAP	Active	Single	40	0.46	80	1.5	40	-	-	SMB-2

For more information please contact your local sales support at www.onsemi.com.

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